

160CMQ...SERIES

Technical Data Data Sheet N1094, Rev. A **Green Products**

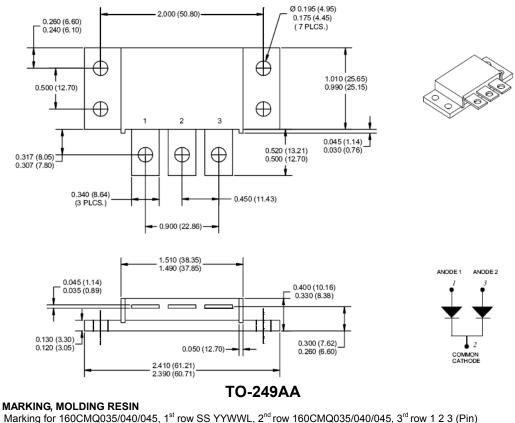
160CMQ...SERIES SCHOTTKY RECTIFIER

Applications:

• Switching power supply • Converters • Free-Wheeling diodes • Reverse battery protection Features:

- 150 °C T_J operation
- Isolated heatsink
- Low profile, high current package
- Center tap module
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions: In mm/Inches



Marking for 160CMQ035/040/045, 1st row SS YYWWL, 2nd row 160CMQ035/040/045, 3rd row 1 Where YY is the manufacture year

WW is the manufacture week code L is the wafer's Lot Number

Molding resin

Epoxy resin UL: 94V-0

China - Germany - Korea - Singapore - United States

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Characteristics	Symbol	Condition		Max.	Units
Peak Repetitive Reverse Voltage	V _{RRM}		35	160CMQ035	
Working Peak Reverse Voltage	V _{RWM}	-	40	160CMQ040	V
DC Blocking Voltage	V _R		45	160CMQ045	
Average Forward Current	I _{F(AV)}	50% duty cycle $@T_c = 71^{\circ}C$, rectangular wave form		160	А
Peak One Cycle Non-Repetitive Surge Current(peg leg)	I _{FSM}	8.3 ms, half Sine pulse		900	А
Non-Repetitive Avalanche Energy(peg leg)	E _{AS}	T _J =25℃,I _{AS} =16A,L=0.84mH		108	mJ
Repetitive Avalanche Current(peg leg)	I _{AR}	Current decaying linearly to zero in 1 µsec Frequency limited by T_J max. V_A =1.5× V_R typical		16	A

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Forward Voltage Drop	V _{F1}	@ 80A, Pulse, T _J = 25 °C	0.64	V
(per leg) *	V F1	@ 160A, Pulse, T _J = 25 °C	0.86	v
	V _{F2}	@ 80A, Pulse, T _J = 125 °C	0.60	V
	V F2	@ 160A, Pulse, T _J = 125 °C	0.76	v
Reverse Current (per leg) *	I _{R1}	$@V_R = rated V_R T_J = 25 \circ C$	5	mA
	I _{R2}	$@V_R = rated V_R$, $T_J = 125 °C$	200	mA
Junction Capacitance (per leg)	CT	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	2600	pF
Typical Series Inductance (per leg)	Ls	Measured lead to lead 5 mm from package body	8.0	nH
Voltage Rate of Change	dv/dt	-	10,000	V/μs

* Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units		
Junction Temperature	TJ	-	-55 to +150	С°		
Storage Temperature	T _{stg}	-	-55 to +150	°C		
Typical Thermal Resistance Junction to Case(per leg)	$R_{ ext{ heta}JC}$	DC operation	1.0	°C/W		
Typical Thermal Resistance Junction to Case (per package)	$R_{ ext{ heta}JC}$	DC operation	0.50	°C/W		
Typical Thermal Resistance, case to Heat Sink	$R_{ hetacs}$	Mounting surface, smooth and greased	0.10	°C/W		
Mounting Torque	Тм	-	40(min)	Ka om		
	IM		58(max)	- Kg-cm		
Approximate Weight	wt	-	58	g		
Case Style	TO-249AA					

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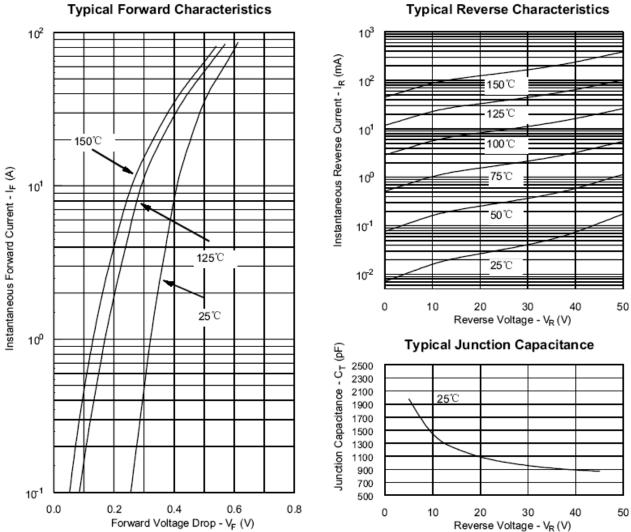
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Typical Reverse Characteristics



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